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FPF1C2P5MF07AM F1 Module solution for PV-Application

General Description

Fairchild's brand-new DC-AC module is designed for a power stage that needs more compact design. And the Press-fit technology provides simple and reliable mounting. This module is optimized for the application such as solar inverter where a high efficiency and robust design are needed.

Electrical Features

- High Efficiency
- Low Conduction and Switching losses
- Low V_{CE(sat)}: 1.1 V typ. @ Ic = 30 A
- Low $R_{DS(ON)}$: 90 m Ω max.
- · Fast Recovery Body Diode

Mechanical Features

- Compact size : F1 Package
- Press-fit contact technology

Applications

Solar Inverter

Certification

• UL approved (E209204)



July. 2014





Internal Circuit Diagram

Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Description		Rating	Units
Rectifier Di	ode			
V _{RRM}	Peak Repetitive Reverse Voltage		620	V
I _{Fav}	Diode Continuous Forward Current	@ T _C = 80°C	27	А
I _{FSM}	Diode Maximum Forward Surge Current		245	А
l ² t	l ² t value		300	A ² s
P _D	Maximum Power Dissipation	@ T _C = 25°C	77	W
TJ	Operating Junction Temperature		-40 to +150	°C

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Symbol Units Description Rating **High-side IGBT** V V_{CES} Collector-Emitter Voltage 620 Gate-Emitter Voltage ± 20 V V_{GES} **Collector Current** @ T_C = 80°C 39 А lc Pulsed Collector Current 90 А I_{CM} Diode Continuous Forward Current I_{F} @ $T_{\rm C} = 80^{\circ}{\rm C}$ 22 А **Diode Maximum Forward Current** 90 А I_{FM} @ $T_{C} = 25^{\circ}C$ 231 W P_D Maximum Power Dissipation -40 to +150 °C T_{J} **Operating Junction Temperature** Low-side MOSFET V V_{DSS} Drain-Source Voltage 620 ± 20 V V_{GSS} Gate-Source Voltage Continuous Drain Current @ $T_{C} = 25^{\circ}C$ 36 А I_D @ $T_{C} = 80^{\circ}C$ 27 А Pulsed Drain Current Limited by T_J max. 156 А I_{DM} Continuous Source-Drain Forward Current 36 А I_{S} Maximum Pulsed Source-Drain Forward Current 156 I_{SM} А P_D Maximum Power Dissipation @ T_C = 25°C 250 W °C ТJ **Operating Junction Temperature** -40 to +150 Module -40 to +125 °C Storage Temperature T_{STG} @ AC 1_{MIN} VISO Isolation Voltage 2500 V Iso. Material Internal Isolation Material Al₂O₃ Mounting Force per Clamp 20 to 50 Ν **F**MOUNT Weight 22 Typ. g Terminal to Heatsink 11.5 mm Creepage Terminal to Terminal 6.3 mm Clearance Terminal to Heatsink 10.0 mm Terminal to Terminal 5.0 mm

Absolute Maximum Ratings T_C = 25°C unless otherwise noted. (Continued)

Package Marking and Ordering Information

Device	Device Marking	Package	Packing Type	Quantity / Tray
FPF1C2P5MF07AM	FPF1C2P5MF07AM	F1	Tray	22

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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Rectifier	Diode					
V _F	Diode Forward Voltage	I _F = 30 A	-	-	1.9	V
		I _F = 30 A @T _C = 125°C	-	1.45	-	V
I _R	Reverse Leakage Current	V _R = 620 V	-	-	25	μA
R _{θJC}	Thermal Resistance of Junction to Case	per Diode	-	-	1.62	°C/W
Liab side	ICPT					
Off Charac	teristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0 V, I_{C} = 1 mA$	620	-	-	V
I _{CES}	Collector Cut-off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	25	μA
I _{GES}	Gate-Emitter Leakage Current	$V_{GE} = V_{GES}, V_{CS} = 0 V$	-	-	2.5	μA
On Charac	teristics					
V _{GE(th)}	Gate-Emitter Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 30$ mA	4	5.7	7	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 30 A, V _{GE} = 15 V	-	1.1	1.6	V
		I _C = 30 A, V _{GE} = 15 V @T _C = 125°C	-	1.0	-	V
		I _C = 60 A, V _{GE} = 15 V	-	1.4	-	V
Switching	Characteristics					-
Qg	Total Gate Charge	V _{DS} = 380 V, V _{GS} = 0V+15 V, I _D = 30 A - 214		-	nC	
Raic	Thermal Resistance of Junction to Case	per IGBT	-	-	0.54	°C/W

High-Side	e FWD					
V_{FM}	Diode Forward Voltage	I _F = 15 A, V _{GS} = 0 V	-	1.75	2.25	V
t _{rr}	Reverse Recovery Time	I _F = 15 A	-	30	-	ns
l _{rr}	Reverse Recovery Current	dI _F /dt = 1650 A/μs	-	27	-	А
Q _{rr}	Reverse Recovery Charge		-	405	-	nC
t _{rr}	Reverse Recovery Time	I _F = 15 A	-	43		ns
I _{rr}	Reverse Recovery Current	dI _F /dt = 1500 A/μs @T _C = 125°C	-	38	-	А
Q _{rr}	Reverse Recovery Charge	_	-	814	-	nC
$R_{ ext{ heta}JC}$	Thermal Resistance of Junction to Case	per Diode	-	-	1.61	°C/W

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Symbol	Parameter Conditions		Min.	Тур.	Max.	Units
Low-Side	MOSFET					
Off Charac	cteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 1 mA	620	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 620 V, V _{GS} = 0 V	-	-	25	μA
I _{GSS}	Gate-Body Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V			2.5	μA
On Charac	teristics					
V _{GS(th)}	Gate-Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_{D} = 250 \text{ mA}$	2.7	3.8	5.3	V
	Static Drain-Source On-Resistance	$I_{\rm D} = 27 \text{ A}, V_{\rm GS} = 10 \text{ V}$	-	-	90	mΩ
20(011)		$I_{D} = 27 \text{ A}, V_{GS} = 10 \text{ V} @T_{C} = 125^{\circ}\text{C}$	-	135	-	mΩ
		$I_{D} = 47 \text{ A}, V_{GS} = 10 \text{ V}$	-	76	-	mΩ
V _{SD}	Source-Drain Diode Forward Voltage	$I_{SD} = 27 \text{ A}, V_{GS} = 0 \text{ V}$	-	-	1.5	V
		I _{SD} = 47 A, V _{GS} = 0 V	-	1.3	-	V
Switching	Charactoristics					
tel(en)	Turn-On Delay Time	V ₀₀ = 380 V	-	57	-	ns
•a(on) t_	Rise Time	$-1_{\rm D} = 27 {\rm A}$	-	14	-	ns
n talat	Turn-Off Delay Time	$-V_{GS} = 10 V$	-	240	-	ns
tr	Fall Time	$=$ R _G = 10 Ω	-	20	-	ns
	Turn-On Switching Loss per Pulse	$T_{c} = 25^{\circ}C$		440	-	uJ
EOFE	Turn-Off Switching Loss per Pulse		-	113	-	uJ
t _{d(on)}	Turn-On Delay Time	V _{CC} = 380 V		53	-	, ns
tr	Rise Time	I _D = 27 A	-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$-V_{GS} = 10 V$	-	257	-	ns
-(0) t _f	Fall Time	$- R_G - 10.52$	-	20	-	ns
E _{ON}	Turn-On Switching Loss per Pulse	$T_{\rm C} = 125^{\circ}{\rm C}$	-	719	-	μJ
E _{OFF}	Turn-Off Switching Loss per Pulse		-	124	-	μJ
Qg	Total Gate Charge	V _{DS} = 380 V, V _{GS} = 0V+10 V, I _D = 27 A	-	155	-	nC
Raio	Thermal Resistance of Junction to Case	per Chip	-	-	0.5	°C/W

Typical Performance Characteristic

Fig 1. Typical Output Characteristics - IGBT











Fig 2. Typical Output Characteristics - IGBT



Fig 4. Transient Thermal Response Curve - IGBT







FPF1C2P5MF07AM F1 Module solution for PV-Application



Typical Performance Characteristic (Continued)

Fig 13. Turn-Off Loss vs. Drain Current - MOSFET

Fig 14. Turn-On Loss vs. Drain Current - MOSFET





















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Definition of Terms		
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